PNP Silicon Epitaxial Transistor

KSB834W

Features

- Complement to KSD880W
- This is a Pb-Free Device

Applications

• Low Frequency Power Amplifier

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-60	٧
V _{CEO}	Collector-Emitter Voltage	-60	٧
V _{EBO}	Emitter-Base Voltage	-7	V
I _C	Collector Current	-3	Α
Ι _Β	Base Current	-0.5	Α
P _C	Collector Dissipation (T _C = 25°C)		W
P _C	P _C Collector Dissipation (T _A = 25°C)		W
TJ	T _J Junction Temperature		°C
T _{STG}	T _{STG} Storage Temperature		°C

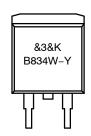
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



- 1. Base
- 2. Collector 3. Emitter

D²PAK-3 (TO-263, 3-LEAD) CASE 418AJ

MARKING DIAGRAM



&3 = Date Code Format &K = Lot Run Traceability Code B834W-Y = Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping [†]
KSB834WYTM	D2PAK-3 (Pb-Free)	800 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

KSB834W

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Characteristic	Test Condition	Min	Тур	Max	Unit
I _{CBO}	Collector Cut-off Current	$V_{CB} = -60 \text{ V}, I_{E} = 0$			-100	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -7 \text{ V}, I_{C} = 0$			-100	μΑ
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -50$ mA, $I_{\rm B} = 0$	-60			V
h _{FE1} h _{FE2}	DC Current Gain	V _{CE} = -5 V, I _C = -0.5 A V _{CE} = -5 V, I _C = -3 A	60 20		200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -3 \text{ A}, I_B = -0.3 \text{ A}$		-0.5	-1	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = -5 V, I _C = -0.5 A		-0.7	-1	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -5 \text{ V}, I_{C} = -0.5 \text{ A}$		9		MHz
C _{cb}	Collector Output Capacitance	V _{CB} = -10 V, I _E = 0, f = 1 MHz		150		pF
t _{ON}	Turn On Time	$V_{CC} = -30 \text{ V}, I_C = -1 \text{ A}, I_{B1} = -I_{B2} = -0.2 \text{ A},$		0.4		μs
t _{STG}	Storage Time	$R_L = 30 \Omega$		1.7		μs
t _F	Fall Time			0.5		μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

\mathbf{h}_{FE} CLASSIFICATION

Classification	0	Y
h _{FE1}	60 ~ 120	100 ~ 200



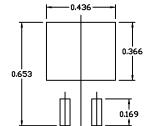


2x 0.063

D²PAK-3 (TO-263, 3-LEAD) CASE 418AJ

ISSUE F

DATE 11 MAR 2021



RECOMMENDED
MOUNTING FOOTPRINT

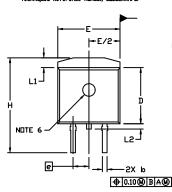
0.100 PITCH

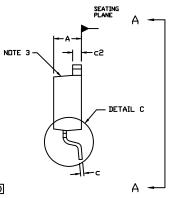
For additional information on our Pb-Free strategy and soldering details, please downlood

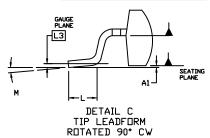
NOTES

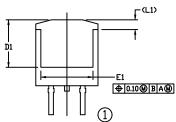
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: INCHES
- 3. CHAMFER OPTIONAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.005 PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE DUTERMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
- 5. THERMAL PAD CONTOUR IS OPTIONAL WITHIN DIMENSIONS E, L1, D1, AND E1.
- 6. OPTIONAL MOLD FEATURE.
- 7. ①,② ... OPTIONAL CONSTRUCTION FEATURE CALL DUTS.

	INCHES		MILLIMETERS	
DIM	MIN.	MAX.	MIN.	MAX.
A	0.160	0.190	4.06	4.83
A1	0.000	0.010	0.00	0.25
ھ	0.020	0.039	0.51	0.99
u	0.012	0.029	0.30	0.74
5	0.045	0.065	1.14	1.65
D	0.330	0.380	8.38	9.65
D1	0.260		6.60	
E	0.380	0.420	9.65	10.67
E1	0.245	-	6.22	
e	0.100 BSC		2.54 BSC	
Ξ	0.575	0.625	14.60	15.88
L	0.070	0.110	1.78	2.79
L1		0.066		1.68
L2		0.070		1.78
L3	0.010	0.010 BSC 0.25 BSC		BSC
М	0*	8*	0*	8*

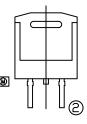


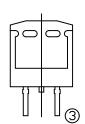


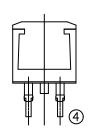




VIEW A-A







VIEW A-A

OPTIONAL CONSTRUCTIONS

XXXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot Y = Year

WW = Work Week

W = Week Code (SSG)

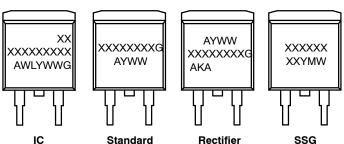
M = Month Code (SSG)

G = Pb-Free Package

AKA = Polarity Indicator

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

GENERIC MARKING DIAGRAMS*



DOCUMENT NUMBER:

98AON56370E

Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DESCRIPTION: D

D²PAK-3 (TO-263, 3-LEAD)

PAGE 1 OF 1

onsemi and ONSemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales